

# isc N-Channel MOSFET Transistor

# IRF3704ZCS

#### FEATURES

- With TO-263( D2PAK ) packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



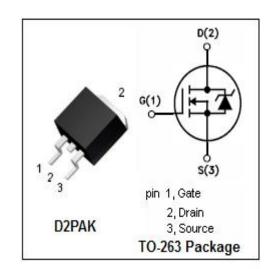
- · Power supply
- · Switching applications

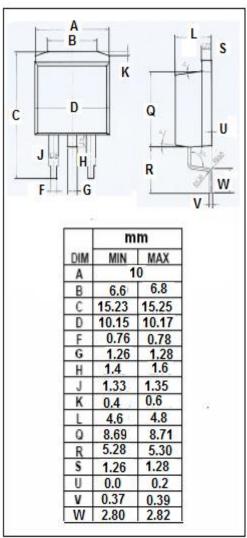


SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	20	V	
V <sub>GSS</sub>	Gate-Source Voltage	±16	V	
I <sub>D</sub>	Drain Current-Continuous;Tc=25℃ Tc=100℃	67 47	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	260	А	
$P_D$	Total Dissipation	57	W	
Tj	Operating Junction Temperature	150	${\mathbb C}$	
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$	

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	2.65	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 0.25mA	20			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.25mA	1.65		2.55	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =21A		6.3	7.9	mΩ
lgss	Gate-Source Leakage Current	V <sub>GS</sub> =±16V;V <sub>DS</sub> =0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 16V; V <sub>GS</sub> = 0V;Tc=25°C V <sub>DS</sub> = 16V; V <sub>GS</sub> = 0V; Tc=125°C			1 150	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =17A, V <sub>GS</sub> = 0 V			1.0	V

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